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TRANSMITTAL FORM

(to be used for all correspondence after initial filing)

Application Number	10/656,802
Filing Date	September 4, 2003
First Named Inventor	Erik Scher
Group Art Unit	1753
Examiner Name	Unassigned
Attorney Docket Number	40-001320US

Total Number of Pages III This Submi	Attorney Docket Number			
	ENCLOSURES (check all that ap	n(v)		
		After Allowance Communication		
Fee Transmittal Form	Assignment Papers (for an Application)	to Group		
Fee Attached	Drawing(s)	Appeal Communication to Board of Appeals and Interferences		
Amendment / Response	Licensing-related Papers	Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)		
After Final	Petition Routing Slip (PTO/SB/69) and Accompanying Petition	Proprietary Information		
Affidavits/declaration(s)	Petition to Convert to a Provisional Application	Status Letter		
Extension of Time Request	Power of Attorney, Revocation Change of Correspondence Address	X Additional Enclosure(s) (please identify below):		
Express Abandonment Request	Terminal Disclaimer	PTO form 1449, cited referenced and receipt		
X Later and Birelander Statement	Small Entity Statement	acknowledgment postcard		
Information Disclosure Statement	Request for Refund			
Certified Copy of Priority Document(s)	Authorization to Charge Deposit Account Please charge Deposit Account No. 50-0893	for any additional fees associated with		
Response to Missing Parts/ Incomplete Application	this paper or during the pendency of this application, including any extensions of time for consideration of the documents enclosed.			
Response to Missing	Remarks			
Parts under 37 CFR 1.52 or 1.53				
SIGNATU	IRE OF APPLICANT, ATTORNEY, OR	AGENT		
Firm or Individual name	Quine, Reg. No. 41,261, Quine Intelle	ectual Property Law Group, P.C.		
Signature South	Ah Quin			
Date January 26, 20				
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Typed or printed name	Juliana Hermes		·
Signature	Solom Klern	Date	January 26, 2004



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QUINE INTELLECTUAL PROPERTY LAW GROUP, P.C.

By Auliana Hermes

Attorney Docket No. 40-001320US Client Ref. No. 01-001320US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Erik Scher, et al.

Application No.: 10/656,802

Filed: September 4, 2003

For: NANOSTRUCTURE AND

NANOCOMPOSITE BASED

COMPOSITIONS AND

PHOTOVOLTAIC DEVICES

Examiner: Unassigned

Art Unit: 1753

INFORMATION DISCLOSURE

STATEMENT UNDER 37 CFR § 1.97 and

§ 1.98

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The references cited on attached form PTO-1449 are being called to the attention of the Examiner. Copies of the references are enclosed. It is respectfully requested that the cited information be expressly considered during the prosecution of this application, and the references be made of record therein and appear among the "references cited" on any patent to issue therefrom.

As provided for by 37 CFR 1.97(g) and (h), no inference should be made that the information and references cited are prior art merely because they are in this statement and no

Erik Scher, et al.

Application No.: 10/656,802

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representation is being made that a search has been conducted or that this statement encompasses all the possible relevant information.

Applicant believes that <u>no fee is required</u> for submission of this statement, since it is being submitted prior to the first Office Action on the merits per 37 CFR 1.97(b)(3). However, if a fee is required, the Commissioner is authorized to deduct such fee from the undersigned's Deposit Account No. 50-0893. Please deduct any additional fees from, or credit any overpayment to, the above-noted Deposit Account.

Respectfully submitted,

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known **Application Number** 10/656,802 September 4, 2003 Filing Date Erik Scher First Named Inventor **Group Art Unit** 1753 Unassigned **Examiner Name** 40-001320US Attorney Docket Number January 26, 2004 **Date Submitted**

(use as many sheets as necessary)

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Examiner Initials	Cite No.	U.S. Patent Docur Number	nent Kind Code (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, lines, Where Relevant Passages or Relevant Figures Appeal
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Examiner Initials	Cite No.	Office	Number	Kind Code (if known)	Name of Patentee or Applicant of Cited Document	of Cited Document MM-DD-YYYY	Where Relevant Passages or Relevant Figures Appear	Ľ
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Complete if Known **Application Number** 10/656,802 September 4, 2003 Filing Date Erik Scher First Named Inventor Group Art Unit 1753 Unassigned **Examiner Name** Attorney Docket Number 40-001320US January 26, 2004 Date Submitted

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23	wo	03/085700	Nanosys, Inc.	10-16-2003	

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Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	1
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